# ■ MN101C49G , MN101C49H , MN101C49K

Туре	MN101C49G	MN101C49H	MN101C49K			
ROM (x8-bit)	128 K	160 K	224 K			
External memory can be expanded						
RAM (×8-bit)	4 K	6 K	10 K			
External memory can be expanded						
Package		QFP100-P-1818B *Lead-free				
Minimum Instruction Execution Time	Standard: 0.10 μs (at 4.5 V to 5.5 V, 20 MHz)  0.238 μs (at 2.7 V to 5.5 V, 8.39 MHz)  125 μs (at 2.0 V to 5.5 V, 32 kHz)*  Double speed: 0.12 μs (at 4.5 V to 5.5 V, 8.39 MHz)  0.25 μs (at 3.0 V to 5.5 V, 4 MHz)  62.5 μs (at 2.0 V to 5.5 V, 32 kHz)*  * The lower limit for operation guarantee for EPROM built-in type is 2.7 V.  * The lower limit for operation guarantee for flash memory built-in type is 4.5 V.					
Interrupts	• RESET • Watchdog • External 0 • External 1 • External 2 • External 3 • External 4 • External 5 • Timer 0 • Timer 1 • Timer 2 • Timer 3 • Timer 4 • Timer 6 • Timer 7 (2 systems) • Time base • Serial 0 • Serial 1 • Serial 2 • Serial 3 • Automatic transfer finish • A/D conversion finish • Key interrupts (8 lines)					
Timer Counter	Clock source ······ 1/2	vent count, generation of remote control 2, 1/4 of system clock frequency; 1/1, ock frequency; 1/1 of XI oscillation clo incidence with compare register 0	1/4, 1/16, 1/32, 1/64 of OSC oscillation			
	Timer counter 1:8-bit × 1 (square-wave output, event count, synchronous output event)  Clock source					
	Timer counter 0, 1 can be cascade-connected.					
	Timer counter 2: 8-bit × 1  (square-wave/8-bit PWM output, event count, synchronous output event, pulse width measurement)  Clock source					
	Timer counter 3: 8-bit × 1 (square-wave output, event count, generation of remote control carrier)  Clock source					
	Timer counter 2, 3 can be cascade-connected.					
	Timer counter 4: 8-bit × 1  (square-wave/8-bit PWM output, event count, pulse width measurement, serial 1 baud rate timer)  Clock source					
	Timer counter 6 : 8-bit freerun timer					
	Clock source ····· 1/	1 of system clock frequency; 1/1, 1/409 equency; 1/1, 1/4096, 1/8192 of XI osc incidence with compare register 6				

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Timer Counter (Continue)		Timer counter 7: 16-bit × 1  (square-wave/16-bit PWM output, cycle / duty continuous variable, event count, synchronous output evevt, pulse width measurement, input capture)  Clock source			
		Time base timer (one-minute count setting)  Clock source			
		Watchdog timer Interrupt source			
		DMA controller (automatic data transfer)  Max. Transfer cycles 255  Starting factor external request, various types of interrupt, software  Transfer mode 1-byte transfer, word transfer, burst transfer			
Serial Interfac	ce	Serial 0 : synchronous type/UART (full-duplex) × 1  Clock source			
		Serial 1 : synchronous type/simple UART (half-duplex) × 1 Clock source ····································			
		Serial 2 : synchronous type × 1  Clock source			
		Serial 3 : synchronous type/simple I <sup>2</sup> C × 1  Clock source ····································			
I/O Pins	I/O	73 • Common use • Specified pull-up resistor available • Input/output selectable (bit unit) (72) ( ): Flash memory built-in type.			
	Input	15 • Common use • Specified pull-up resistor available (14) ( ): Flash memory built-in type.			
A/D Inputs		10-bit × 8-ch. (with S/H)			
D/A Outputs		8-bit × 4-ch.			
Special Ports		Buzzer output, remote control carrier signal output, high-current drive port			

See the next page for electrical characteristics, pin assignment and support tool.

MAD00011DEM Panasonic 2

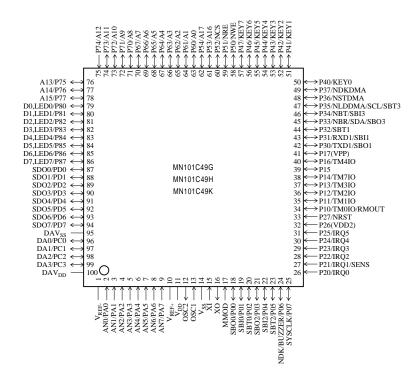
#### **Electrical Characteristics**

#### Supply current

Parameter	Symbol	Condition		Limit		
	Symbol			typ	max	Unit
	IDD1	fosc = 20 MHz, VDD = 5 V		30	70	mA
Operating supply current	IDD2	fosc = 8.39 MHz, VDD = 5 V		15	30	mA
	IDD3	fx = 32.768 kHz, VDD = 3 V		40	120	μΑ
Supply current at HALT	IDD4	fx = 32 kHz, VDD = 3 V (5 V), Ta = 25°C		5 (13)	11 (30)	μΑ
	IDD5	fx = 32.768 kHz, VDD = 3 V (5 V), Ta = 85°C (70°C)			30 (90)	μА
Supply current at STOP	IDD6	VDD = 5 V, Ta = 25°C			3	μΑ
	IDD7	VDD = 5 V, Ta = 85°C (70°C)			60	μΑ

( ): Flash memory built-in type.

#### Pin Assignment



QFP100-P-1818B \*Lead-free

( ): Flash memory built-in type.

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### **Support Tool**

In-circuit Emulator	PX-ICE101C / D + PX-PRB101C49-QFP100-P-1818B	
EPROM Built-in Type	Туре	MN101CP49K
	ROM (× 8-bit)	224 K
	RAM (× 8-bit)	10 K
	Minimum instruction execution time	Standard: 0.10 μs (at 4.5 V to 5.5 V, 20 MHz)
		$0.25~\mu s$ (at $2.7~V$ to $5.5~V,8.39~MHz)$
		Double speed: $0.12~\mu s$ (at $4.5~V$ to $5.5~V$ , $8.39~MHz$ )
		$0.25~\mu s$ (at $3.0~V$ to $5.5~V, 4~MHz)$
	Package	QFP100-P-1818B *Lead-free
Flash Memory Built-in Type	Туре	MN101CF49K [ES (Engineering Sample) available]
	ROM (× 8-bit)	224 K
	RAM (× 8-bit)	10 K
	Minimum instruction execution time	Standard: 0.10 μs (at 4.5 V to 5.5 V, 20 MHz)
		Double speed: $0.12~\mu s$ (at 4.5 V to 5.5 V, 8.39 MHz)
	Package	QFP100-P-1818B *Lead-free

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